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EXAMINER:

GROUP ART UNIT:

TITLE: Nitride Metal Oxide Semiconductor Integrated Transistor Devices

ASSISTANT COMMISSIONER FOR PATENTS

ALEXANDRIA, VA 22313

37 CFR 1.115 PRELIMINARY AMENDMENT

Sir:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begin on page 3.

Remarks/Arguments begin on page 4 of this paper: